

Scattering of X-ray Ultrashort Laser Pulses on Bound Electrons in Dense Plasma

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Abstract: We considered the resonance scattering of ultrashort laser pulses (USLP) on the bound electrons of hydrogen-like ions in a dense plasma. A process description was proposed in terms of full scattering probability during the time of pulse action. Dense plasma's effect was demonstrated at the resonance scattering cross-section spectrum, and the probability dependence on USLP carrier frequency and duration was obtained for the cases of isolated ions and ions in a dense plasma.

Keywords: ultrashort laser pulses; dense plasma; bound electrons; resonance scattering; fine structure

1. Introduction

Plasma physics operates according to the statistical properties of systems consisting of many charged particles, where Coulomb forces on collective effects play a significant role [1]. With increasing electron density, plasma acquires the properties of condensed matter, and the neglect of short-distance forces becomes incorrect. Thus, the subject of consideration is a strongly correlated Coulomb system in which quantum statistics, as well as dynamic effects, should be taken into account [2,3]. Hence, building a proper theoretical model describing dense plasma processes can address problems related to nuclear, atomic, and molecular physics. The solution to this issue demands lots of experimental data. One of the most efficient methods for studying classic plasma parameters is laser diagnostics. For high-density matter sensing with the appropriate spatial and time resolution, ultrashort x-ray pulse generation is essential [4]. USLP's duration is too small to consider it monochromatic. Generally, the probabilistic models of laser-matter interaction operate according to the notion of probability per unit of time with monochromatic and stationary photon flux [5]. Thus, these models should be reconsidered.

Works describing ultrashort-pulse interactions with atomic systems in terms of probability and full probability during the pulse action exist. For example, in [6], the authors dealt with quasi-stationary non-monochromatic radiation that made it possible to introduce probability per unit of time and consider constant energy flux. Thus, the description of the interaction in terms of the scattering of the cross-section normalized on the spectral width of the non-monochromatic radiation is valid. However, such an approach does not consider pulse duration. Our model considers non-stationary radiation flux and allows researching the dependencies of photoprocessing characteristics on the pulse duration. The authors of [7–9] studied the interaction of subcycle pulses with quantum systems at durations much less than the characteristic time of electron oscillations. Photoprocesses' probability dependence on pulse duration was described in detail. Another work dealing with sudden perturbation approximation proposed a description of a wide class of photoprocesses in the field of USLP [10,11]. Nevertheless, the approach presented in [7–9] is applicable only for subcycle pulses as well as sudden perturbation approximation, upon which the work carried out in [10,11] rely, and is valid for USLP durations much lower than the inner atomic process time. The model we suggest has no restriction in terms of the cycle number or duration of USLP and could be universalized in various systems.



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The general formulas of ultrashort laser pulse (USLP) scattering on atoms were obtained in [12]. A later work [13] was devoted to the consideration of femtosecond pulse resonance scattering on atoms in plasma. In the present paper, we presented a model of ultrashort laser pulse (USLP) resonance scattering on bound electrons in dense plasma, which was formulated in terms of the full probability during the time of pulse action. We assessed the full probability dependence on USLP carrier frequency and duration. Special attention was paid to the particularities of dependencies defined by high plasma density.

2. General Formulas

To calculate the full probability of photoprocessing in the field of USLP during pulse action, we used the following Formula [12]:

$$W_{sc} = \frac{c}{4\pi} \int_0^{+\infty} \frac{|E(\omega, \omega_c, \tau)|^2}{\hbar\omega} \sigma_{sc}(\omega) d\omega. \tag{1}$$

where c —speed of light in vacuum and \hbar —Planck constant. We consider the Gauss shape of USLP electric field strength Fourier transform $E(\omega, \omega_c, \tau)$:

$$E(\omega, \omega_c, \tau) = \sqrt{\frac{\pi}{2}} E_0 \tau \exp\left(-\frac{(\omega - \omega_c)^2 \tau^2}{2}\right). \tag{2}$$

where E_0 —electric field amplitude, and ω_c, τ —carrier frequency and duration of USLP, respectively.

Equation (1) enables a connection between the full probability and scattering cross-section σ_{sc} . In the framework of dipole approximation, the scattering cross-section could be expressed through dynamic polarizability β [5]:

$$\sigma_{sc}(\omega) = \frac{8\pi}{3} \left(\frac{\omega}{c}\right)^4 |\beta(\omega)|^2. \tag{3}$$

The scope of the present work determining the scattering of bound electrons. The Feynman diagram, illustrating this process, is presented in Figure 1 [14].

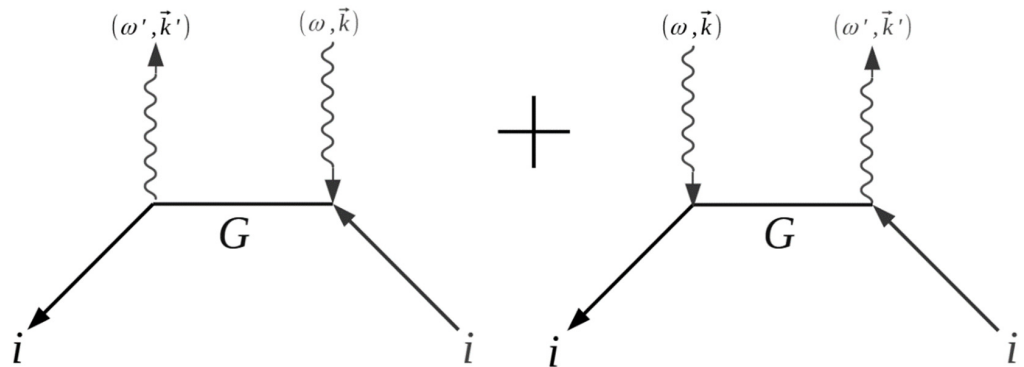


Figure 1. Feynman diagram of scattering of bound electrons.

An absorbing photon with a four-wavevector (ω, \mathbf{k}) electron is transmitted from the state $|i\rangle$ into the virtual state $|j\rangle$, after which it returns to the initial state $|i\rangle$, reradiating the absorbed photon with four-wavevector (ω', \mathbf{k}') . In the case of resonance scattering, only resonance virtual states $|j\rangle$ contribute to the Green function of a bound electron.

In the present paper, we considered resonance transitions from the ground state $1s$ to np -shells in hydrogen-like ions, taking into account their fine structure.

The dependence of dynamic polarizability on the frequency of transition $1s \rightarrow np$ with the allowance of fine-structure splitting could be described by the following formula [13]:

$$\beta(\omega) = \frac{e^2}{m_e} \left(\frac{f_{np_{1/2}1s}}{\omega_{np_{1/2}1s}^2 - \omega^2 - 2i\omega A_{n1}} + \frac{f_{np_{3/2}1s}}{\omega_{np_{3/2}1s}^2 - \omega^2 - 2i\omega A_{n1}} \right). \tag{4}$$

where e —electron charge and m_e —electron mass. The spectral line of an atom is determined by three parameters: oscillator strength f_{ij} , transition frequency ω_{ij} , and Einstein coefficient of spontaneous transition A_{ij} .

As ions are involved in thermal motion, spectral lines are subjected to Doppler broadening. To consider this fact, we average $|\beta(\omega)|^2$ over the ion velocity projections v_x on the direction of the wave vector of the incident photon following the Maxwell distribution [13]:

$$\langle |\beta(\omega)|^2 \rangle_D = \sqrt{\frac{m_i}{2\pi T_i}} \frac{e^4}{m_e^2} \int_{-\infty}^{\infty} \left| \frac{f_{np_{1/2}1s}}{\left(\frac{\omega_{np_{1/2}1s}}{1-v_x/c}\right)^2 - \omega^2 - 2i\omega A_{n1}} + \frac{f_{np_{3/2}1s}}{\left(\frac{\omega_{np_{3/2}1s}}{1-v_x/c}\right)^2 - \omega^2 - 2i\omega A_{n1}} \right|^2 \exp\left(-\frac{m_i v_x^2}{2T_i}\right) dv_x. \tag{5}$$

where T_i —ion temperature in eV. In the present work, we consider equilibrium plasma ($T_e = T_i$).

The final formula for the scattering cross-section on bound electrons for ions involved in chaotic thermal motion is as follows:

$$\sigma_{sc}^{(be)} = \frac{8\pi}{3} \left(\frac{\omega}{c}\right)^4 \langle |\beta(\omega)|^2 \rangle_D. \tag{6}$$

Thus, the knowledge of atomic transition parameters and USLP parameters along with Formulas (1), (2), (5), and (6) provide descriptions of USLP scattering on bound electrons in terms of the full probability during pulse action.

In the case of isolated hydrogen-like ions, line parameters could be calculated by simple analytical Expressions (7)–(9).

A rigorous formula for oscillator strength is as follows [14]:

$$f_{npj,1s} = n^5 \frac{2^8 (n-1)^{(2n-4)} g_j}{3(n+1)^{(2n+4)} \sum_j g_j}. \tag{7}$$

where g_j is the statistical weight of the state with the full electron momentum equal to j .

The strict quantum mechanical description of motion in the centrally symmetric field gives the formula for transition frequency [14]:

$$\omega_{npj,1s} = \frac{m_e c^2}{\hbar} \left[\left(1 + \frac{(Z\alpha)^2}{\left(\sqrt{\left(j + \frac{1}{2}\right)^2 - (Z\alpha)^2} + n - j - \frac{1}{2}\right)^2} \right)^{-\frac{1}{2}} - \sqrt{1 - (Z\alpha)^2} \right]. \tag{8}$$

where α —fine structure constant and Z —the atomic number.

The Einstein coefficient for a spontaneous transition between the state with the main quantum number n and the ground state is described by the following rigorous formula [14]:

$$A_{n1} = Z^4 \alpha^3 \frac{2^8 n(n-1)^{(2n-2)} Ry}{9(n+1)^{(2n+2)} \hbar} \tag{9}$$

where Ry—Rydberg.

In the case of dense plasma, delocalized electron shielding has a sufficient impact on the parameters of the spectral line. Using the finite temperature ion sphere model, the authors of [15] investigated how plasma screening affects the parameters of atomic electron transitions. In particular, under the dipole approximation, they calculated spectral radiative transition rates and oscillator strengths as well as estimated correction terms to transition frequencies. Spectral line parameters for $1s \rightarrow np_j$ transitions in Si^{13+} ion, published in [15], are presented in Table 1 for $n = \{2, 3, 4\}$ and $j = \{1/2, 3/2\}$ for dense plasma. Besides, for comparison, it contains line parameters for isolated ions calculated by Formulas (7)–(9).

Table 1. Spectral line parameters for $1s \rightarrow np$ transitions (f_{npj1s} , ω_{npj1s} , A_{n1}) in Si^{13+} ions for the case of dense plasma at different values of plasma electron density and temperatures [15] as well as for isolated ions.

	Transition	ω_{npj1s} , eV	f_{npj1s}	A_{n1} , s ⁻¹
$n_e = 8.7 \times 10^{22} \text{ cm}^{-3}$ $T_e = 189 \text{ eV}$	$1s \rightarrow 2p_{1/2}$	2004.444	0.1383	2.411×10^{13}
	$1s \rightarrow 2p_{3/2}$	2006.193	0.2748	2.416×10^{13}
$n_e = 2.06 \times 10^{23} \text{ cm}^{-3}$ $T_e = 251 \text{ eV}$	$1s \rightarrow 2p_{1/2}$	2004.124	0.1381	2.411×10^{13}
	$1s \rightarrow 2p_{3/2}$	2006.386	0.2746	2.416×10^{13}
$n_e = 8.36 \times 10^{23} \text{ cm}^{-3}$ $T_e = 353 \text{ eV}$	$1s \rightarrow 2p_{1/2}$	2002.303	0.1379	2.405×10^{13}
	$1s \rightarrow 2p_{3/2}$	2003.938	0.2710	2.411×10^{13}
$n_e = 2.76 \times 10^{24} \text{ cm}^{-3}$ $T_e = 439 \text{ eV}$	$1s \rightarrow 2p_{1/2}$	1999.166	0.1370	2.388×10^{13}
	$1s \rightarrow 2p_{3/2}$	2001.373	0.2740	2.393×10^{13}
Isolated ion	$1s \rightarrow 2p_{1/2}$	2004.848	0.1387	2.410×10^{13}
	$1s \rightarrow 2p_{3/2}$	2006.600	0.2775	
$n_e = 8.7 \times 10^{22} \text{ cm}^{-3}$ $T_e = 189 \text{ eV}$	$1s \rightarrow 3p_{1/2}$	2374.872	0.0259	6.345×10^{12}
	$1s \rightarrow 3p_{3/2}$	2375.385	0.0520	6.392×10^{12}
$n_e = 2.06 \times 10^{23} \text{ cm}^{-3}$ $T_e = 251 \text{ eV}$	$1s \rightarrow 3p_{1/2}$	2373.365	0.0258	6.344×10^{12}
	$1s \rightarrow 3p_{3/2}$	2373.874	0.0516	6.391×10^{12}
$n_e = 8.36 \times 10^{23} \text{ cm}^{-3}$ $T_e = 353 \text{ eV}$	$1s \rightarrow 3p_{1/2}$	2369.118	0.0230	5.645×10^{12}
	$1s \rightarrow 3p_{3/2}$	2369.575	0.0463	5.683×10^{12}
Isolated ion	$1s \rightarrow 3p_{1/2}$	2376.636	0.0264	6.434×10^{12}
	$1s \rightarrow 3p_{3/2}$	2377.115	0.0527	
$n_e = 8.7 \times 10^{22} \text{ cm}^{-3}$ $T_e = 189 \text{ eV}$	$1s \rightarrow 4p_{1/2}$	2502.064	0.0078	2.115×10^{12}
	$1s \rightarrow 4p_{3/2}$	2502.273	0.0157	2.113×10^{12}
Isolated ion	$1s \rightarrow 4p_{1/2}$	2506.690	0.0097	2.623×10^{12}
	$1s \rightarrow 4p_{3/2}$	2506.909	0.0193	

The advantage of the described method is the simplicity of the numerical calculations. The simulations do not require any sophisticated algorithms and could be performed with the use of an ordinary PC.

3. Results and Discussion

Figure 2 demonstrates the scattering cross-section calculated with the use of data presented in Table 1. Among the all considered plasma conditions, only in the case of $1s \rightarrow 2p$ transition was fine splitting distinguishable (Figure 2a). In cases $1s \rightarrow 3p$ and $1s \rightarrow 4p$, the fine structure blurred as the gap between the peaks of the fine structure was commensurable with Doppler broadening ($\omega_{np_{3/2}1s} - \omega_{np_{1/2}1s} \sim \sqrt{\frac{2T_e}{m_i}} \frac{\omega_{np1s}}{c}$).

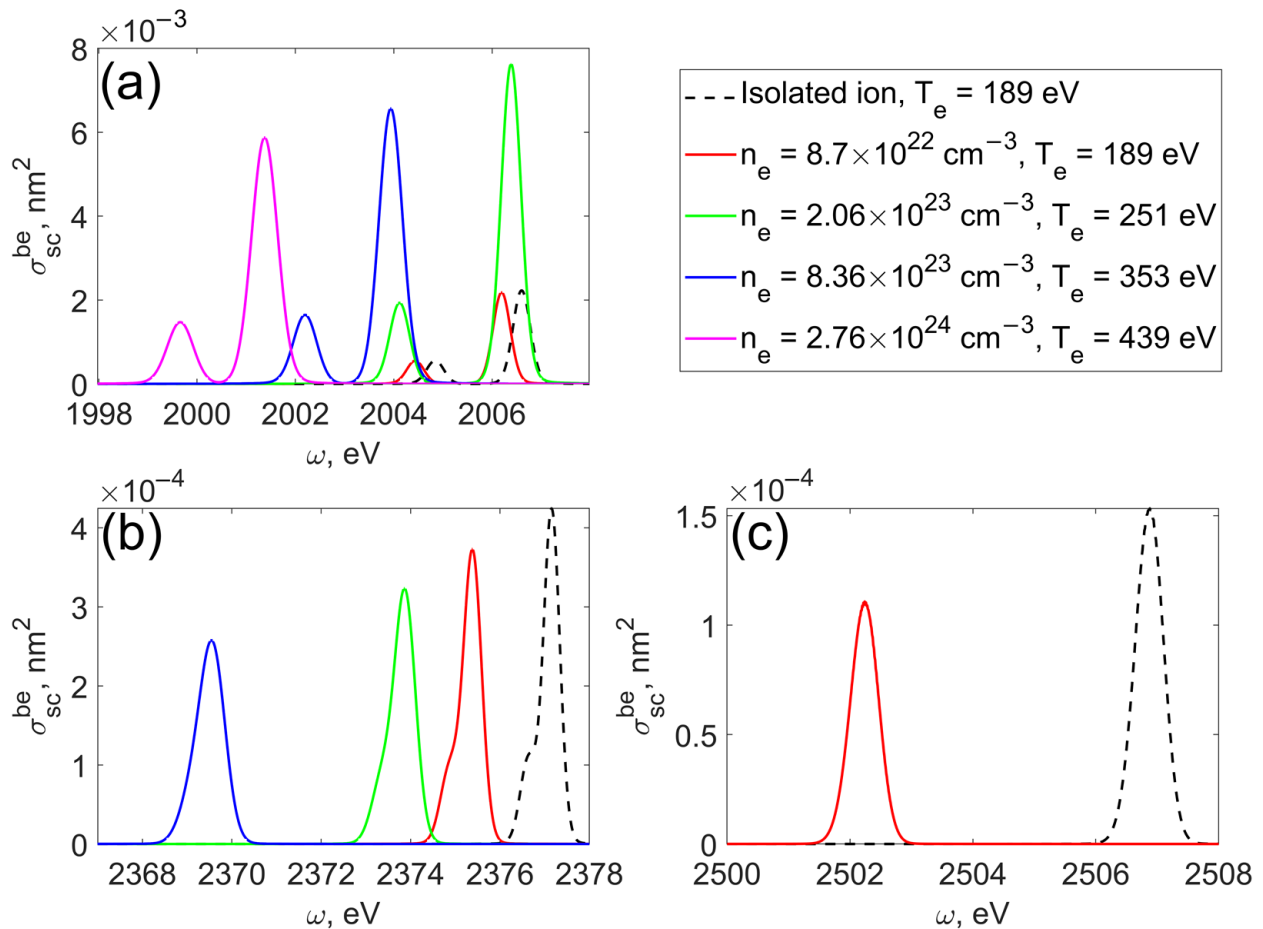


Figure 2. Resonance scattering cross-section spectrum for electron transition in Si^{13+} ion: $1s \rightarrow 2p$ (a), $1s \rightarrow 3p$ (b), and $1s \rightarrow 4p$ (c). Solid lines correspond to calculations for ions shielded by dense plasma, and dashed lines represent the calculations for isolated ions.

The screening of Coulomb interactions induced by the plasma environment affects the atomic structure and radiative atomic data. Hence, the phases and amplitudes of continuum wave functions change. Thus, according to the configuration interaction method, the energy of considered levels decreases. The latter is clearly expressed by the red shift of spectral peaks at the electron density increase in relation to the graphs plotted for isolated ions in accordance with Formulas (5)–(9). Exclusion is the $1s_{1/2} \rightarrow 2p_{3/2}$ transition, whose frequency increases at the density increase from $8.7 \cdot 10^{22} \text{ cm}^{-3}$ to $2.06 \cdot 10^{23} \text{ cm}^{-3}$ (green spectral peak with higher frequency in Figure 2). In this case, level $2s_{1/2}$ undergoes a larger energy shift than other levels as its wavefunction is more sensitive to changes in the plasma shield. Configuration interaction of $1s_{1/2}$ and $2s_{1/2}$ leads to a more significant energy decrease of $1s_{1/2}$ energy than $2p_{1/2}$ and $2p_{3/2}$. As a result, the energy gap between $1s_{1/2}$ and $2p_{3/2}$ is greater than for other transitions [16].

Figure 3a demonstrates the dependence of the resonance scattering probability by bound electron on USLP carrier frequency at the variation of electron plasma density. It

is clearly seen that the dynamics of the $W_{sc}(\omega_c)$ profile are identical to the cross-section dynamic illustrated in Figure 2. Figure 3b demonstrates how the $W_{sc}(\omega_c)$ profile changes according to pulse duration variation. At durations in order of 0.1 fs, dependence had a bell-shaped curve, almost symmetric about the frequency of the $1s_{1/2} \rightarrow 2p_{3/2}$ transition. With the increase in the pulse duration, the USLP spectrum narrowed, and for carrier frequencies near the $1s_{1/2} \rightarrow 2p_{1/2}$ transition frequency, the scattering probability component corresponding to transition $1s_{1/2} \rightarrow 2p_{3/2}$ decreased. Thus, with an increase in the pulse duration, the maximum corresponding to $1s_{1/2} \rightarrow 2p_{1/2}$ appeared.

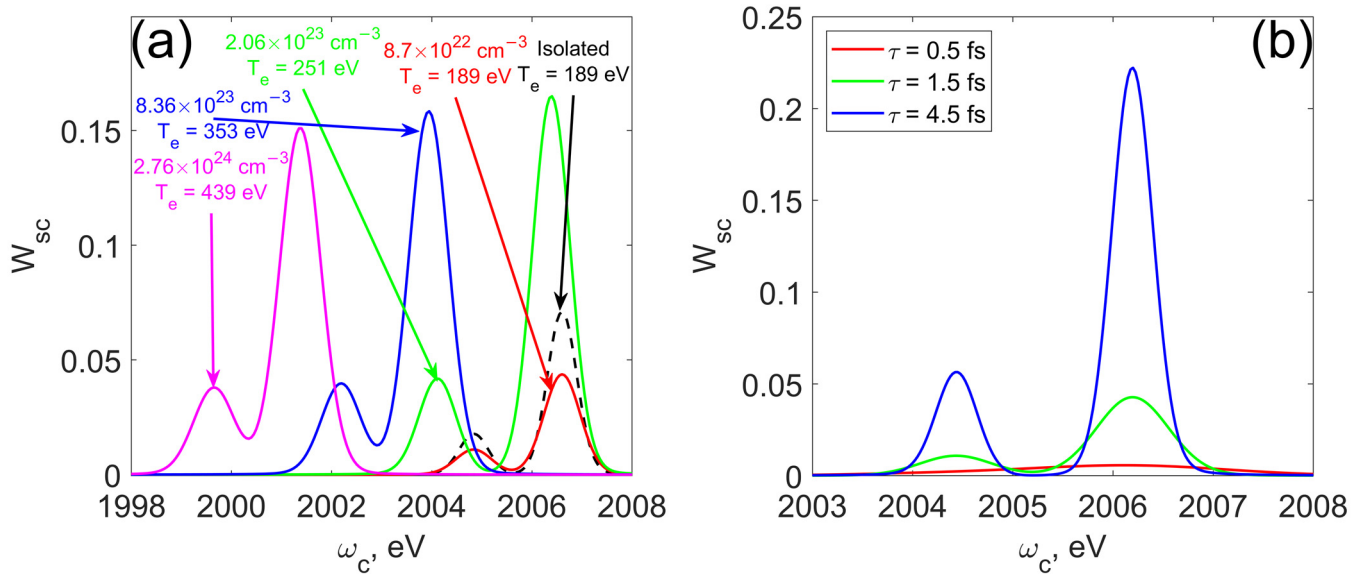


Figure 3. Dependence of resonance USLP scattering probability on carrier frequency in the vicinity of $1s \rightarrow 2p$ transition frequency at various plasma densities for $\tau = 1.5 \text{ fs}$ (a) and USLP durations (b) for $n_e = 8.7 \cdot 10^{22} \text{ cm}^{-3}$, $T_e = 189 \text{ eV}$ (b). $E_0 = 1 \text{ a.u.}$

The probability dependence on the USLP duration (τ -dependence) had different trends at durations $\tau \sim 1 \text{ fs}$, including non-monotonic (Figure 4). When carrier frequency was in the vicinity of spectral maximum (green line in Figure 4), the τ -dependence monotonically grew. Greater $\sigma_{sc}^{(be)}(\omega_c)$ corresponds to a greater steepness of $W_{sc}(\tau)$. From a certain detuning of ω_c from a maximum of $\sigma_{sc}^{(be)}(\omega)$, the τ -dependence became non-monotonic. In the vicinity of $\tau \sim 1 \text{ fs}$, the maximum and minimum appeared (i.e., the magenta curve in Figure 4). The mechanism of non-monotonic dependence at small τ USLP comprises non-monotonic changes of the integral value $\int \sigma_{sc}^{(be)}(\omega) |E(\omega)|^2 d\omega$, to which probability (1) is proportional, due to the commensurability of the scattering cross-section and USLP spectral width. When the carrier frequency was out of the spectral maximum vicinity and the scattering cross-section was negligibly small, the probability was nonzero at small durations (cyan line in Figure 4) as the USLP spectral width was large enough to overlap with the scattering cross-section maxima. As the USLP duration increased, the overlapping degree of $\sigma_{sc}^{(be)}(\omega)$ and $|E(\omega)|^2$ decreased, and the τ -dependence tended to zero.

Density affects the τ -dependency trend (Figure 5). As discussed above, as the density increased, peaks of $W_{sc}(\omega_c)$ shifted. Thus, nonmonotonic trends are shown. Greater plasma density corresponds to less τ^{\max} and τ^{\min} values according to the local maximum and minimum of τ -dependence. As the peak of $W_{sc}(\omega)$, to which the isolated case ω_c is oriented, shifted, the magnitude of τ -dependence decreased.

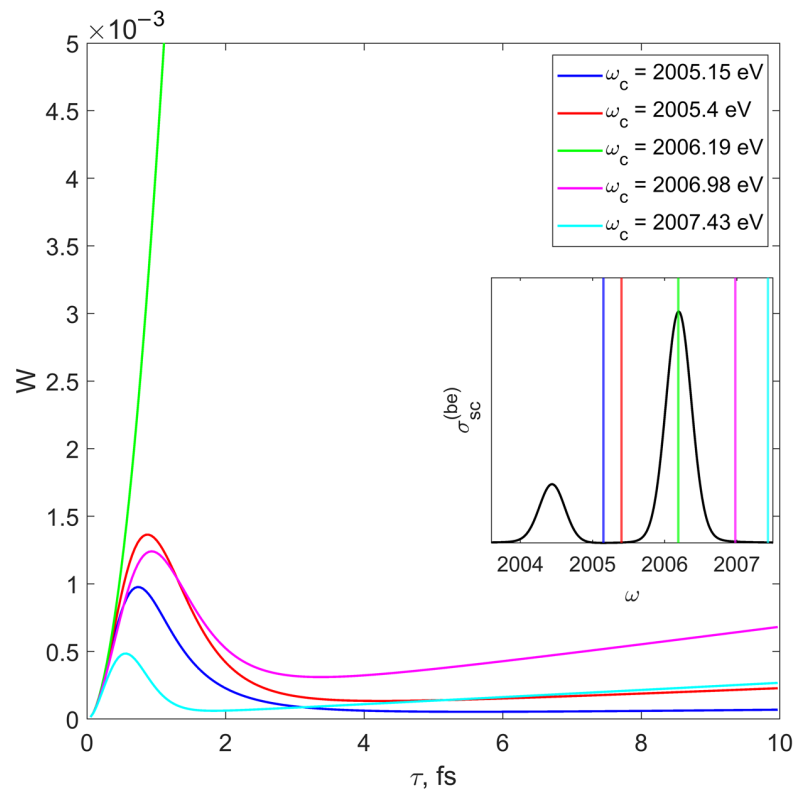


Figure 4. τ -dependence of USLP scattering probability on bound electrons in dense plasma for carrier frequencies in the vicinity of $1s \rightarrow 2p$ transition frequency. The subplot illustrates carrier frequency positions in relation to the scattering cross-section spectra. $n_e = 8.7 \cdot 10^{22} \text{ cm}^{-3}$, $T_e = 189 \text{ eV}$, $E_0 = 1 \text{ a.u.}$

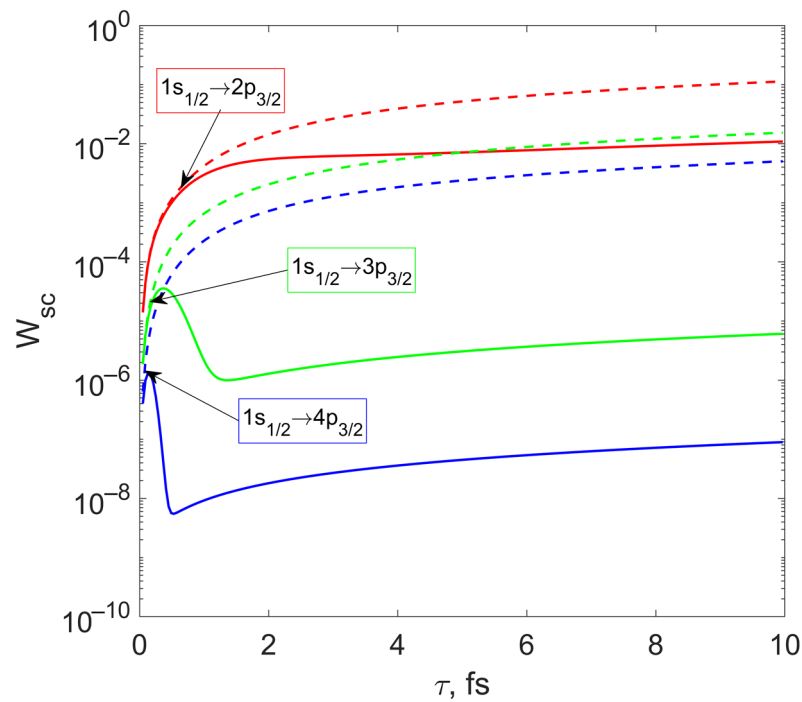


Figure 5. τ -dependence of the scattering probability on bound electrons of ions in dense plasma (solid lines) and for isolated ions (dashed lines). Transitions $1s_{1/2} \rightarrow np_{3/2}$ are considered at $T_e = 189 \text{ eV}$ and in the case of the shield ion at electron density $n_e = 8.7 \cdot 10^{22} \text{ cm}^{-3}$. USLP carrier frequency corresponds to the maximum of $W(\omega_c)$ dependence in the case of isolated ions.

4. Conclusions

In the present paper, we studied the particularities of resonance ultrashort laser pulse scattering on bound electrons in dense plasma. Studying the cross-section spectra and dependency of resonance scattering probability on USLP carrier frequency and duration, we determined the effects of dense plasma.

Due to dense plasma screening, cross-section spectrum and probability dependence on the carrier frequency, in general, had a redshift as the density increased. We considered the dependence of scattering probability on USLP duration (τ -dependence) and demonstrated that, in general, it is not a monotonic function. Separately, we showed that as the plasma density increased, the τ -dependence trend became non-monotonic and USLP durations, corresponding to extremums, decreased. Along with this, the scattering probability magnitude radically decreased.

Typical trends of τ -dependence were herein assessed. We demonstrated that for carrier frequency in the vicinity of spectral maximum, τ -dependence monotonically rises, and the greater the scattering of the cross-section, the greater the steepness of τ -dependence. At the carrier frequencies detuned from the the spectral maximum for a certain value, the local maximum and minimum of the considered function appeared due to the complex τ -dependence of the overlapping area between the scattering cross-section and the USLP spectrum. If the cross-section value at the carrier frequency was negligibly small, τ -dependence was nonzero at low pulse durations due to the broad USLP spectrum.

In the example $1s \rightarrow 2p$ transition in Si^{13+} ions, we assessed full scattering probability as a function of carrier frequency and established that as the USLP duration decreases, the dependence profile broadens and at after a certain duration, the fine splitting of the atomic energy level becomes indistinguishable.

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